



## 28th RD50 Workshop (Torino)

### Wednesday, 8 June 2016

#### Radiation Damage II - Aula Magna della Cavallerizza Reale (11:00 - 12:45)

-Conveners: Juozas Vaitkus

time	[id] title	presenter
11:00	[15] Study of surface radiation damage of segmented Si sensors at Hamburg University: Results, status and next steps	Dr SCHWANDT, Joern
11:20	[18] Generation shallow radiation damages at the strip surface with low energy protons.	Mr WONSAK, Sven
11:40	[27] Electric field, mobility and trapping in Si detectors irradiated with neutrons and protons up to $1e17 \text{ n}_{\text{eq}}/\text{cm}^2$	Prof. MIKUZ, Marko
12:00	[28] TCT measurements of n-type MCz diodes after irradiation with 70 MeV protons and 300 MeV pions	Mr HOLMKVIST, William
12:20	[41] Characterization of neutron irradiated pad detectors using a Transient Current Technique based on the Two Photon Absorption process (TPA-TCT)	Mr FERNANDEZ GARCIA, Marcos